

Power MOSFETs

Application Note 832

ThermaSim[™] On-Line Thermal Simulation for Vishay Siliconix Power MOSFETs

By Kandarp Pandya

Introduction

Vishay's new ThermaSim[™] is a free on-line tool that helps designers speed time to market by allowing detailed thermal simulations of Vishay Siliconix power MOSFETs to be performed before prototyping. Useful for any power MOSFET application, ThermaSim is ideal for high-current, high-temperature, SMD (surface mount device) applications such as automotive, fixed telecom, desktop and laptop computers, and industrial systems. The tool is available at <u>http://www.vishay.com/thermal-modelling</u>.

This application note is a walk-through for each step in a ThermaSim simulation. For ease of understanding and comparing with on-line displays, this document uses the following style:

- Section headings and special notes are in Italic Bold
- Sub-sections and item descriptions, as seen on screen displays, before actions are in **Bold**

Vishay recommends first reading through the entire document, then for an organized and efficient thermal analysis, using the "Appendix A" worksheet to collect all the necessary information for your specific analysis.

"Appendix B" through "Appendix E" cover various working examples. Starting with the worksheets for each case, the corresponding results follow, with detailed indexes for the examples given in the summary section.

Registration

First time users must register on Vishay's web site. Use the link <u>http://www.vishay.com/registration</u> to begin (see Figure 1). **Fill-in** the registration information, and a user password will be emailed to you. The "New Thermal Simulation" link under the MOSFET section on Vishay's web site (Figure 2 and 2A) also takes users to the log-on page (Figure 3).

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ThermaSim[™] On-Line Thermal Simulation for Vishay Siliconix Power MOSFETs

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VISHAY PRODUCTS	COMPANY INFO		
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irt a customized parametric :	earch or find a datasheet by using the links below.		Sales Offices
age	Drain-to-source voltage (V _{DS})	Type and configuration	(i) Related Information
) FOOT [®] (17)	N-channel (568)	ASM - Application Specific MOSFETs (13	Technical Materials
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iA (6)	30 V and below (369)	Battery switch devices (20)	MOSFETs application notes
) (50)	20 V to 40 V (401)	Current sensing (4)	New Thermal Simulation Package Comparisons
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		Figure 2.	
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	argest manufacturers of ors and passive components		Part or keyword O Inventory & quote
VISHAY PRODU			
application, ThermaSim will be In order to use ThermaSim, you More About ThermaSim In a first for on-line MOSFET sii tool also allows you to define o	ion Tool free tool that helps you speed time to market by allowing detailed especially useful in high-current, high-temperature applications s must first register on the Vishay Website. If you want to register, o hulation, ThermaSim [™] uses structurally detailed models of Visha her heat-dissipating components and simulate their effect on the he set-up is comprehensive. Use ThermaSim to construct the PC the power dissipation profile, system temperature, air flow, and a	d thermal simulations of Vishay Siliconix power MOSFETs to be pe such as automotive, fixed telecom, desktop and laptop computers, or if you have already registered and want to use ThermaSim, click ay Siliconix power MOSFETs created using finite element analysis MOSFET's thermal operation. Simulating these components ensu 28 size, layers, material, and copper spreading; set pad size and s assembly orientation with respect to gravity to correctly account for utiliple results with varying product, package, or other input data can	and industrial systems. Inere. (FEA) techniques to increase the simulation's accuracy. The res optimum device selection for application specification older quality; define the heat sink size, material, and the effect of convection. You also have a choice between to emerged within Microsoft® Excel® to compare and example
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ThermaSim[™] On-Line Thermal Simulation for Vishay Siliconix Power MOSFETs

Address 🐻 H	http://www.vishay.com/thermal-modelling
	One of the world's largest manufacturers of
VISHAY.	discrete semiconductors and passive components
	VISHAY PRODUCTS COMPANY INFO
_	
Thermal	Simulation - Log In
Vou must b	e logged in to use this feature.
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Load 1:	Components >> 2: PCB >> 3: Position >> 4: System >> 5: Setup >> 6: Run 3: Plate 3: mail
STEP 1: COM	APONENTS SELECTION
	ows the selection of one or several components in the Vishay products list and several other components that will be used for the thermal
simulation. Th	e power specification zone allows the specification of a power profile dissipated by the component.
Vishay prod	uds Other components Components Selection List
search	
in family	
Add	S11302DL S11303DL S1303ED
	SII304DL SII305DL
Power spe	te. Haat sink spec
and the second second	y state value 0 W
O step ir	nput (transient)
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Ocycles	s (transient)
	ON value 0 W
	period 0 s
	ratio 0 Delete Copy Paste
	ratio 0 Delete Copy Paste Specify power

APPLICATION NOTE



ThermaSim[™] On-Line Thermal Simulation for Vishay Siliconix Power MOSFETs

Log-In

Log-on using the link <u>http://www.vishay.com/thermal-modelling</u> (Figure 3) with your email address and password. The web tool should open as shown in Figure 4.

Tab 1: Components

This section enables the selection of thermal models for Vishay Siliconix power MOSFETs from a built-in library. If applicable, specify the MOSFET's power profile and heat sink. Also, define other heat dissipating components and specify its power.

Vishay Products: There are three options for selecting a Vishay component:

a) Search Field: Enter the part number in the search field.
Scroll down the list adjacent to the "Add" icon, the part will be *highlighted* (Figure 5).
If the thermal model is not available in the library, the part search will fail to display the highlighted part as

part search will fail to display the highlighted part, as shown in Figure 6.

b) **By Family:** The pull down menu lists different packages (Figure 7).

Scroll down to the package.

Select package (For example, select **SO-8 S** for the SOIC single part family).

Scroll down the list that shows parts in the selected package family (Figure 8).

Select the part to *highlight*.

c) Pull-Down Menu: Directly use the pull-down menu adjacent to the "Add" icon.
 Scroll down to the part number.
 Select the part as shown in Figure 9.

Using any one of the three methods listed above, *select* the part. *Do not* try to add the part to the design by clicking the "Add" icon. Doing so will result in an error window (Figure 10). However, before adding a part to the design, you must first define the power specifications (value and/or profile).

Power Specs: The "Power Spec" tab, located at the lower left of the page, enables the power profile definition for each component. Three options are available to set the power profile for either steady-state or one of the two transient simulation modes. **Select** the **"Power Specs"** tab to define power using any one of the three tabs:

a) Steady-State Value:

Click the radio button to select the steady-state mode. Enter the steady-state value in the corresponding box (see Figure 11). The simulation in this mode predicts the steady-state values of the component and PCB temperatures. The result provides maximum and minimum die (silicon) temperatures, top and bottom surface temperatures of both the component and the PCB, and the flux (power dissipated) through the PCB.

b) Step Input (Transient) On Value:

Click the radio button to select the step input (transient) mode.

Enter the step input (transient) on value in the corresponding **box** (see Figure 12).

This simulation mode predicts the transient thermal behavior of the component mounted on the defined PCB and with other system definitions. The results show the temperature excursion through a predefined period and time steps. The step transient simulation definition is completed in the "Systems" tab, "Simulation Settings" sub-menu.

Please note that in order to maintain a reasonable computational time with on-line access and operation of the FEA-based system, it is necessary to impose the following input value limitations for step transient simulation:

• Step Input Power Value in W: 0.1 ≤ Power Value ≤ 100.

With incorrect values, an error message window will appear indicating value limits, as shown in Figure 13.

c) Cycle Transient On Value:

Click the **radio button** to select the **cycle transient** input mode (see Figure 14.

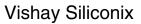
- Enter cycle transient values:
- On value in the corresponding box.
- Period in the corresponding box (time of one cycle).
- **Ratio** in the corresponding **box** (ratio of on-time to off-time).

The results show the temperature excursion through a predefined time duration and time steps. The step transient simulation definition is completed in the "Systems" tab, "Simulation Settings" sub-menu.

Please note that in order to maintain a reasonable computational time with on-line access and operation of the FEA-based system, it is necessary to impose the following input value limitations for cyclic transient simulation:

- Power Value in W: $0.1 \le$ Power Value ≤ 1000 .
- Period in Seconds: $0.01 \le Period \le 2000$.
- *Ratio:* $0.01 \le Ratio \le 1$.

With incorrect values, an error message window will appear indicating value limits, as shown in Figures 15, 16, and 17.





Add Vishay component (MOSFET part) to Design: After defining the power specs, click the Add icon to add the part to the design. The "Component Selection List" displays the part with its power specs, as shown in Figure 18.

Other Components (Heat Dissipating): This menu facilitates defining and adding other heat dissipating components, such as resistors and inductors, to the design. Thus, the simulation can take into account the effect of the heat dissipated by these components on the thermal performance of the Vishay Siliconix power MOSFET under study (refer to Figure 19).

Name: Enter a name for the heat-dissipating component. The default name for the component starts with 'Component1.'

Enter the dimensions in mm:

- Size (lx) Enter the value in the corresponding box.
- Size (ly) Enter the value in the corresponding box.
- Size (lz) Enter the value in the corresponding box.

The defaults values for thermal conductivity, density, and specific heat are good enough for first level of analysis. However, using the correct values, if known, can improve the accuracy of simulation results. Please note the units of each parameter while modifying the values:

- Conductivity Modify the value in the corresponding box.
- **Density** Modify the value in the corresponding **box**.
- Specific Heat Modify the value in the corresponding box.

Next, define the average power dissipation for this component using the steady-state value icon as follows (see Figure 11):

Click the radio button to select the steady-state mode. Enter the steady-state value in the corresponding box.

Click the "Add" icon to add the other component1 to design.

The "Component Selection List" displays component1 with power specs, as shown in Figure 20.

To **add more than one Vishay component,** or **other heat-dissipating components,** follow the same procedure described in the preceding discussions. If there is more than one component with the same part number, it is possible to use editorial commands as shown below (refer to Figure 21).

Copy and Paste a Part in the Design:

Select (highlight) the part in the "Component Selection List."

Click the **"Copy"** icon to copy the part in the clipboard. **Click** the **"Paste"** icon to add the copied part to the design. The "Component Selection List" updates to add the part.

Edit a Part in the Design:

Select (highlight) the part in the "Component Selection List." Select "Power Specs" to edit the power specification for

the part. Modify the information as required.

Click on the **"Specify Power"** icon. The "Component Selection List" updates the selected part.

Delete a Part in the Design:

Select (highlight) the part in the "Component Selection List."

Click the "Delete" icon.

The "Component Selection List" will update to remove the part from the design.

Heat Sink Specs: The tab next to "Power Specs," located in the lower left of the page, enables the attachment of a heat sink on top of the MOSFET component selected from the "Component Selection List." In addition, it allows the removal or editing of the attached heat sink. *Please note that at this time, the simulation can define only simple, plate heat sinks with X-Y-Z dimensions. (It is not possible to define heat sinks with fins).*

Specify Heat Sink:

Select a component from the "Component Selection List" as shown in Figure 22. The component will be **highlighted**. Next, go to the "Specify Heat Sink" sub-tab.

Size (lx) - Enter the length in the corresponding box in mm. Size (ly) - Enter the width in the corresponding box in mm. Size (lz) - Enter the thickness in the corresponding box in mm.

Select Heat Sink Material: Aluminum or copper are the two options offered by the pull-down menu.

Select Heat Sink Attachment Method: Solder, glue, and mica are the three options under the pull-down menu.

Click on the "Specify Heat Sink" icon.

The "Component Selection List" will update to append the highlighted component with the heat sink information (see Figure 23).

Remove Heat Sink From Design:

Select a component with a heat sink from the "Component Selection List" as shown in Figure 23. The component will be highlighted.

Click on the **"Remove Heat Sink"** icon. The ""Component Selection List"" will update to delete the heat sink information from the highlighted component.

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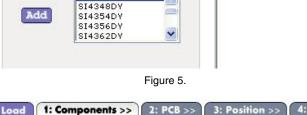
Edit Heat Sink Properties:

Select a component with a heat sink from the "Component Selection List" as shown in Figure 23. The component will be **highlighted.**

Edit the parameter information in the "Heat Sink Specs" area.

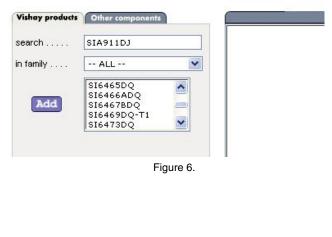
Click on the **"Specify Heat Sink"** icon. The "Component Selection List" will update the highlighted component with the edited heat sink information.







This page allows the selection of one or several components in the Vishay proc simulation. The power specification zone allows the specification of a power pr





STEP 1: COMPONENTS SELECTION

This page allows the selection of one or several components in the Vishay proc simulation. The power specification zone allows the specification of a power pr

in family	ALL	¥
Add	ALL 1206-8 ChipFET D 1206-8 ChipFET S D2PAK (TO-263) SUB D2PAK (TO-263) SUM D2PAK (TO-252) S DPAK (TO-252) S DPAK (TO-252) S BVAK (TO-252) S BVA	^
	PPAK SO-8 D PPAK SO-8 S	
Power spec.	PPAK SO-8 S BWL	
 ● steady stat 	PPAK-ChipFET Reverse DPAK Reverse DPAK BWL	
Ostep input (SC 70-3L SC 70-6L D SC 70-6L S	
O cycles (trai	SO-8 D SO-8 D BWL SO-8 S SO-8 S BWL	
	SO-8 S plus Sch SOT-23 /SSOT-23 TSOP-6D TSOP-6S	*



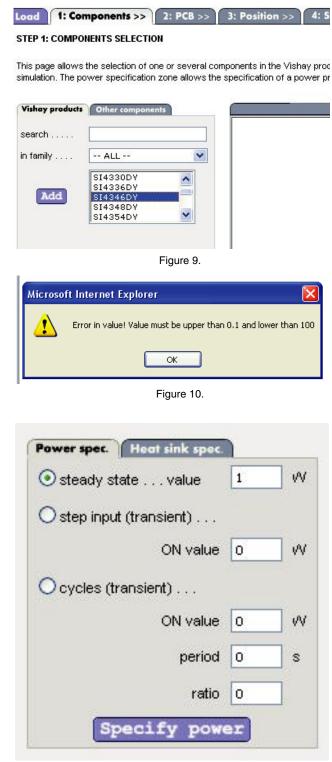
STEP 1: COMPONENTS SELECTION

This page allows the selection of one or several components in the Vishay proc simulation. The power specification zone allows the specification of a power pr





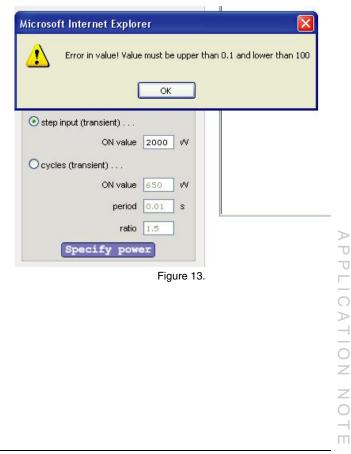
ThermaSim[™] On-Line Thermal Simulation for Vishay Siliconix Power MOSFETs





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Figure 12.





ThermaSim[™] On-Line Thermal Simulation for Vishay Siliconix Power MOSFETs

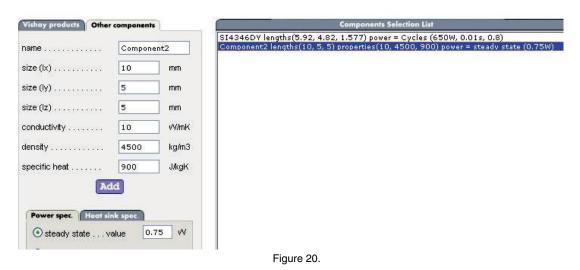
Power spec. Heat sink spec.	Microsoft Internet Explorer
O steady state value 0 W	Error in period! Period must be upper than 0.01 and lower than 2000
Ostep input (transient)	ОК
ON value 0 W	⊙ cycles (transient) ON value 650 W
⊙cycles (transient)	period 5000 s
ON value 650 VV	Specify power
period 0.01 s	Figure 16.
ratio 0.80	Microsoft Internet Explorer
Specify power	Error in ratio! Ratio must be upper than 0.01 and lower than 1
Figure 14.	ОК
Aicrosoft Internet Explorer	ON value 650 W
Error in value! Value must be upper than 0,1 and lower than 1000	period 0.01 s
	Specify power
Ocycles (transient)	Figure 17.
ON value 4500 VV	Viskey products Other components Search SI4346DY lengths(5:92, 4:82, 1:577) power = Cycles (650W, 0:01s; 0:85
period 0.01 s	in family
Specify power	Add \$143480v \$143440v \$143540v \$143560v \$14362v
Figure 15.	Figure 18.



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Vishay products Other	components	
name	Componen	t2
size (lx)	10	mm
size (ly)	5	mm
size (lz)	5	mm
conductivity	10	WinK
density	4500	kg/m3
specific heat	900	J/kgK
Ad	d	







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Vishay products	Other components		Components Selection List
name	Componer	iti 👘	SI4346DY lengths(5.92, 4.82, 1.577) power = steady state (1W) Component1 lengths(5, 5, 2) properties(10, 4500, 900) power = steady state (0.75W) SI4346DY lengths(5.92, 4.82, 1.577) power = steady state (0.5W)
size (lx)	5	mm	Component1 lengths(5, 5, 2) properties(10, 4500, 900) power = steady state (0.5w)
size (ly)	5	mm	
size (lz)	2	mm	
conductivity	10	w/mK	
density	4500	kg/m3	
specific heat	900	J/kgK	
Power spec.	ransient) ON value 0	·••	
O cycles (tran	ON value	w	
	period 0		
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Spec	cify power		Next >>

Figure 21.

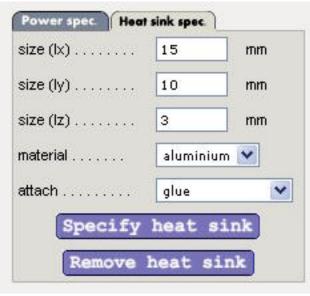


Figure 22.



ishay products	Other components	Components Selection List
earch family	ALL	SI4368DY lengths(5.92, 4.82, 1.577) power = steady state (1W) heat sink(10, 8, 3, alumin Component1 lengths(5, 5, 2) properties(10, 4500, 900) power = steady state (0.75W) SI4368DY lengths(5.92, 4.82, 1.577) power = steady state (0.5W) Component1 lengths(5, 5, 2) properties(10, 4500, 900) power = steady state (1W)
Add	SI4368DY SI4370DY SI4376DY SI4376DY SI4378DY SI4384DY	
Power spec.		
size (ly)	8 mm	
size (ly) size (lz) material	3 mm	

Figure 23.

Click on "Tab 2: PCB" at the top of the page to go to the next section.

Alternatively, **clicking** on the "**Next**" icon at the bottom of the page also takes you to "**Tab 2: PCB.**"

Tab 2: PCB

In this section, the printed circuit board information relevant for thermal analysis is input. A visual aid dynamically displays a representative structure of the PCB. The information includes length and width, and the top, bottom, and internal layers' thickness in mm. The pull-down menu offers options for material and percentage coverage (for copper). In addition, include a via zone to specify thermal via information.

PCB Size:

Default values for size X and size Y are 100 mm (refer to Figure 24). Enter the length in the size X box. Enter the width in the size Y box. Click the "Apply" icon. The board displays the changes proportionally. **Standard PCB:** This pull-down menu allows you to choose available standard PCBs. This can be time saving if any of the available options meet the desired PCB specs.

Layer Definition:

Top Layer: The material for the top layer is either copper or none.

This sub-tab has a pull-down menu.

Select material from none, or 10 % copper through 100 % copper with percentage coverage (see Figure 25). Enter the top layer thickness in the corresponding box in mm (refer to Figure 24).

Click anywhere outside of the "Layer Definition" tab. The PCB picture updates dynamically.

Refer to Table 1 for copper thickness in oz., and the corresponding measurements in mm, of the external layer as per IPC 2201. Please note that the thickness of the copper for the internal layer is different from external layers.





TABLE 1 - EXTERNAL CONDUCTORTHICKNESS AFTER PLATING

BASE COPPER FOIL	MINIMUM
1/8 oz.	20 µm
1/4 oz.	20 µm
3/8 oz.	25 μm
1/2 oz.	33 µm
1 oz.	46 µm
2 oz.	76 µm
3 oz.	107 μm
4 oz.	137 μm
5	copper foil, increase minimum mess by 30 μm

Internal Layer: The material for the internal layer is either FR-4 epoxy/glass or copper.

This sub-tab has a pull-down menu.

Select the material from FR-4 epoxy/glass, or 10 % copper through 100 % copper with percentage coverage (see Figure 26 and 27).

Enter the layer **thickness** in the corresponding **box** in mm. **Click** anywhere outside of the "Layer Definition" tab. The PCB picture updates dynamically.

Refer to Table 2 for copper thickness in oz., and the corresponding measurements in mm, of the **internal layer** as per IPC 2201.

	NTERNAL LAYER FOIL S AFTER PROCESSING
COPPER FOIL	MINIMUM
1/8 oz	3.5 µm
1/4 oz	6.0 μm
3/8 oz	8.0 μm
1/2 oz	12.0 μm
1 oz	25.0 μm
2 oz	56.0 μm
3 oz	91.0 μm
4 oz	122.0 μm
Above 4 oz	13 μm below minimum thickness listed for that foil thickness in IPC-MF-150

Click on the **"Add"** icon to add the layer to the design. The box will list the layer and the display will reflect the changes.

Click anywhere outside of the "Layer Definition" tab. The PCB picture updates dynamically.

Edit Commands for Layers:

"Delete," "Copy," "Paste," and "Modify" icons remove, add, and edit a layer. Figure 28 shows internal layers for FR-4, 1.5-mm thick, 4-layer board.

Delete a Layer:

Select a layer from the selection list. It will be highlighted. Click on the "Remove" icon. The selection list will update to delete the layer.

Copy and Paste a Layer/s:

Select a layer from the selection list. It will be highlighted. Click on the "Copy" icon. Click on the "Paste" icon. The selection list will update to add the layer.

Modify a Layer:

Select a layer from the selection list. It will be highlighted. Modify material or layer thickness as required. Click on the "Modify" icon. The selection list will update to modify the selected layer.

Bottom Layer: This is a duplication of the top layer. The material for the bottom layer is also copper or none. This sub-tab has a pull down menu.

Select the material from none, or 10 % copper through 100 % copper with percentage coverage (see Figure 25).

Enter the bottom layer's thickness in the corresponding **box** in mm (refer to Figure 24).

Click anywhere outside of the "Layer Definition" tab. The PCB picture updates dynamically. Figure 29 is an example of a FR-4, 1.5-mm thick, 4-layer PCB.

Via Definition: Most practical designs use via arrays, under and/or around the part, to improve thermal efficiency of a PC board design. Use the "**Via**" tab to specify the **via zone**, and include via array information. The via zone is a rectangular area, which includes the via array. Refer to Figure 30.

Select the "Via" tab. The via menu page opens.

Via Zone Dimensions:

Enter size X (mm) in the corresponding box. Enter size Y (mm) in the corresponding box.



Via Zone Position (center location on the PCB): Enter position X (mm) in the corresponding box. Enter position Y (mm) in the corresponding box.

Diameter of One Via: Enter internal diameter (mm) in the corresponding box. Enter external diameter (mm) in the corresponding box.

Number of Via on:

X-axis - Enter number in the corresponding box. Y-axis - Enter number in the corresponding box.

Select Material Inside Via: SnPb or air are the two choices in the pull-down menu.

Click on the **"Add Via Zone"** icon. The via zone information appears in the box below the **via list.** The graphical display also updates with the via zone (refer to Figure 30, a PCB picture updated with a 20-mm x 10-mm via zone located in the center.

Edit Commands for Via Zones:

Modify Position:

Select a via zone from the list.
Enter position X (mm) in the corresponding box.
Enter position Y (mm) in the corresponding box.
Click the "Modify Position" icon.
The PCB figure interactively changes to display the new position for the via zone.
Alternatively, select a via zone from the list.
Pick, drag, and drop the selected via zone to new position on the PCB.
Copy and Paste:
Select a via zone from the list to highlight.
Click on the "Copy" icon.
Click on the "Paste" icon.
The selection list will update to add the via zone.
Use "Modify Position" steps to reposition the via zone on the PCB.

Delete Via Zone: Select a via zone from the selection list. It will be highlighted. Click on the "Delete" icon. The selection list will update to delete the via zone. The graphical display changes interactively.

STEP 2: PCB DEFINITION

This page allows the definition of the Printed Circuit Board. PCB can be entierly by the copper coverage. Internal layers determine the internal structure of the

PCB size:			
size x	100	mm	Apply
size y	100	mm	
Standard PCB:			
Stanuaru PCD:			
Stanuaru PCD:	1×1 2	ayers 💌 🌘	Apply
			Apply
Top layer Internal layers Bottom	layer Y V		Apply
	layer V	ias	Apply

Figure 24.

STEP 2: PCB DEFINITION

This page allows the definition of the Printed Circuit Board. PCB can be entirely by the copper coverage. Internal layers determine the internal structure of the

PCB size:			
size x	50	mm	Apply
size y	25	mm	
Standard PCB:			
	18121	avers 💙	Apply

 Top layer
 Internal layers
 Bottom layer
 Vias

 material
 copper 100% ♥

 thickness
 none

 copper 20%

 copper 30%

 copper 50%

 copper 70%

 copper 70%

 copper 90%

 copper 100%

Figure 25.



ThermaSim[™] On-Line Thermal Simulation for Vishay Siliconix Power MOSFETs

STEP 2: PCB DEFINITION

This page allows the definition of the Printed Circuit Board. PCB can be entienly by the copper coverage. Internal layers determine the internal structure of the

PCB size:	-		
size x	50	mm	Apply
size y	25	mm	
Standard PCB:			
	181 2	ayers 💙	Apply
Top layer Internal layers Bo	ottom layer 🍸 V	lias	10 × 1
	FR-4 Epoxy		
material	FR-4 Epoxy	/Glass 💙	Add
naterial	-		Add
naterial	FR-4 Epoxy	/Glass 💙	Add
naterial	FR-4 Epoxy	/Glass 💙	Add
	FR-4 Epoxy	/Glass 💙	Add

STEP 2: PCB DEFINITION

This page allows the definition of the Printed Circuit Board. PCB can be entirely by the copper coverage. Internal layers determine the internal structure of the

PCB size:		
size x	50	
size y	25	mm
Standard PCB:		
	181 2	ayers 💌 🗛 Apply
material FR	-4 Epoxy	'Glass 💙 🛛 💻
	-4 Epoxy, 163	'Glass ♥ Add mm
thickness	163 : thickne	mm Add
thickness0.4 Layer 1 material = FR-4 Epoxy/Glass Layer 2 material = copper 90% thic Layer 3 material = FR-4 Epoxy/Glass	+63 thickne kness = 0 thickne	mm Add ss = 0.463 .035 ss = 0.463
thickness	+63 thickne kness = 0 thickne kness = 0	mm Add ss = 0.463 .035 ss = 0.463 .035
thickness	+63 thickne kness = 0 thickne kness = 0	mm Add ss = 0.463 .035 ss = 0.463 .035

Figure 28.

STEP 2: PCB DEFINITION

This page allows the definition of the Printed Circuit Board. PCB can be entirely by the copper coverage. Internal layers determine the internal structure of the

Figure 26.

PCB size:					
size x		50	mn	n [Ann]	
size y		25	mn	n	2
Standard PCB:					
		181 2	avers 📩	Appl	v
Top layer Internal layers	Bottom I	ayer V	as		
	-	ayer V -4 Epoxy/		×	
material	FR	-4 Ероху/ 4 Ероху/	Glass	Add	1
material	FR FR- cop	-4 Ероху/	Glass	Add	4
material	FR FR- cop cop	-4 Epoxy/ 4 Epoxy/ per 10% per 20% per 30%	Glass	Add	1
material	FR FR cop cop cop cop	-4 Epoxy/ 9 Epoxy/ 9 per 10% 9 per 20% 9 per 30% 9 per 40%	Glass	Add	4
material	FR Cop Cop Cop Cop Cop	-4 Epoxy/ 9 er 10% 9 er 20% 9 er 30% 9 er 40% 9 er 50%	Glass	Add	E
material	FR Cop Cop Cop Cop Cop Cop	-4 Epoxy/ 9 Epoxy/ 9 per 10% 9 per 20% 9 per 30% 9 per 40% 9 per 50% 9 per 60%	Glass	Add	F
material	FR Cop Cop Cop Cop Cop Cop Cop	-4 Epoxy/ per 10% per 20% per 30% per 40% per 50% per 60% per 70%	Glass	Add	F
Top layer Internal layers material	FR Cop Cop Cop Cop Cop Cop Cop Cop	-4 Epoxy/ 9 Epoxy/ 9 per 10% 9 per 20% 9 per 30% 9 per 40% 9 per 50% 9 per 60%	Glass	Add	1

Figure 27.



STEP 2: PCB DEFINITION

This page allows the definition of the Printed Circuit Board. PCB can be entienly built or standard PCBs can be loaded. Top and bottom layers are defined by the copper coverage. Internal layers determine the internal structure of the board. Vias can also be defined.

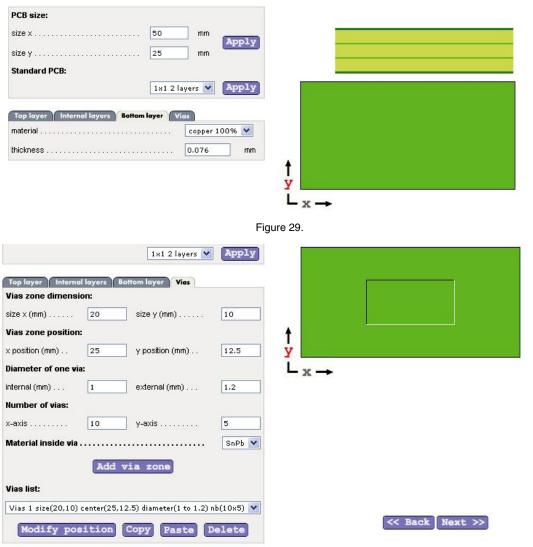


Figure 30.

Click on "Tab 3: Position" at the top of the page to go to the next section.

Clicking on the **"Next"** icon at the bottom of the page also takes you to "Tab 3: Position."

Tab 3: Position

This section allows for the placement of components on the PCB, the definition of the component's pad size, and PCB solder definition. The PCB solder definition facilitates evaluating the effect of solder voids.

Place a Component: Refer to Figure 31. Select a component from the "Component Selection List." Enter component positions X (center) in the

corresponding box in mm. Enter component positions Y (center) in the corresponding box in mm. Click the "Apply" icon.

The PCB picture interactively updates to move the selected component to its new location.

for Vishay Siliconix Power MOSFETs

Pick, Drag, and Drop Command (Alternative):

Select a component from the **"Component Selection List."** The corresponding component will be highlighted in both list as well as on the PCB.

Pick, drag, and drop the highlighted component to the desired location with your mouse's left button.

Change Default Pad Sizes:

Select a component from the "Component Selection List." Enter pad size (lx) in the corresponding box in mm. Enter pad size (ly) in the corresponding box in mm. Click the "Apply" icon.

The PCB picture interactively updates to include the new pad (centered around) for the selected component.

PCB Solder Definition: Define solder quality in this section to account for possible air pockets or voids in the solder joint. The default is 100 % solder, 0 % air.

Select a component from the "Component Selection List." Select one of the four solder definitions from pull-down menu (see Figure 32). The options are: (a) 100 % solder, 0 % air, (b) 90 % solder, 10 % air, (c) 80 % solder, 20 % air, and (d) 70 % solder 30 % air.

Click the "Apply" icon.

This applies property changes internally in the design database. *There will not be any changes in the PCB graphics.*

K Back Next >>

STEP 3: POSITION

This page allows the localization of the components on the Printed Circuit Board. For dynamical position, one click to select the component, move the component and one click to stop the selection. Before moving the components, the size of the PCB must be set. The pad size for each component is parameterizable in this section.

ThermaSim[™] On-Line Thermal Simulation

y 10 mm ly	Co SI4346DY center(25,1 Component1 center(10,	mponents Selection List 2.5) pad(10,8) PCBsol 12.5) pad(7,7) PCBsol	der 100%solder0 der 100%solder0	<mark>Sair</mark> 36 air
y	Components position	5:		
Pad size: x	x		mm Apr	
10 mm 10 mm 10 mm 10 mm PCB solder definition: Image: Comparison of the second se	y	12.5	mm	
ly 8 mm PCB solder definition:	Pad size:			
ly	×			10
	ly			
100%solder0%air V Apply	PCB solder definition:			
		100%solder0%ai	Apr	цу

Figure 31.





APP

ThermaSim[™] On-Line Thermal Simulation for Vishay Siliconix Power MOSFETs

Components positions	:			
x		25	mm	Apply
у		12.5	mm	
Pad size:				
lx		5.92	mm	Apply
ly		4.82	mm	mppri
PCB solder definition:				
		der0%air 🔽	·	Apply
	100%solo			
	90%solde			
80%solder20%air				
	70%solde	r30%air		

Figure 32.

Click on "Tab 4: System" at the top of the page to go to the next section.

Clicking on the **"Next"** icon at the bottom of the page also takes you to "Tab 4: System."

Tab 4: System

This section allows you to specify the ambient temperature and the orientation of the PCB and airflow if applicable. Also, you can specify additional simulation settings for transient simulation. *The "Enclosed Environment" tab is inactive at this time;* however, it is a provision for future features.

Infinite Environment: This tab covers convection definitions (refer to Figure 33).

Enter Ambient Temperature in the corresponding **box** in °C.

Click the "Free Convection" radio button.

The Adjacent pull-down menu on the right side offers three options for PCB orientation:

- Z gravity for a PCB with the component on the top side (see the interactive picture on the right side in Figure 33).
- -Z gravity for an upside down PCB with the component on the bottom side (see the interactive picture on the right side in Figure 34).
- **XY gravity** for a PCB with a vertical orientation (see the picture in Figure 35).

In a system with air flow, select the "Air Flow" radio button.

The adjacent pull-down menu offers six options for the direction of airflow:

- Z to -Z direction for air blowing on top of the component (see Figure 36).
- -Z to Z direction for air blowing from the bottom with the component on the top side (see Figure 37).

- X to -X direction for air blowing right to left over the PCB and component (See Figure 38).
- -X to X direction for air blowing left to right over the PCB and component (see Figure 39).
- Y to -Y direction for air blowing over the PCB in -Y direction over the component (see Figure 40).
- **-Y to Y direction** for air blowing over the PCB in +Y direction over the component (see Figure 41).

Enter the value of the airflow's **normal velocity** in the adjacent **box** in meters per second (refer to Figure 41).

Enclosed Environment: *This is inactive at this time.* It is a provision for a feature we intend to offer in the future.

Simulation Settings: Complete the definitions of steady-state or transient simulations settings in this section. **Select** the **"Steady-State"** radio button as shown in Figure 42 for steady-state simulations.

There are four steps to complete for transient simulation settings (refer to Figure 43).

Select the "Transient" radio button.

Enter the value for initial time in the adjacent box. This helps to keep the file size smaller and speeds up the simulation process. Please note that the *initial time value is always lower than final time*.

Enter the value for final time in the adjacent box.

Click the "Next" icon at the bottom of the page to check if the entry is correct.

An error message window will pop up for a wrong entry. Figure 44 is an example of an error message for the mismatch of final time and time step. The mistake here is *final time/time step* = 100/0.01 = 10000. This is more than 2000 limit.

Click "OK."

Correct the entry, and proceed.

Enter the value of the **time step** in the adjacent **box** (see Figure 43).

Click the "**Next**" icon at the bottom of the page to check if the entry is correct.

An **error message window** will **pop up** for a wrong entry, as shown in Figure 45. Here a value of 0.001 for the time step is lower than the *minimum limit of 0.01*. **Click "OK."**

Correct the entry, and proceed.

Please note that all of the above-mentioned limitations > help to limit the simulation size and time, which is very = important for an on-line simulation.



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STEP 4: SYSTEM DEFINITION

This page allows the definition of the environment of the system: Infinite or enclosed environment. Today only infinite environment is av free convection and air flow modes.

Convection definition:	
mbient temp 25 °C	
gravity orientation	
Dair flow -	→
flow orientationz to -z direction 💌	9
normal velocity (m/s)	et je
	PPAKSOBS SC



STEP 4: SYSTEM DEFINITION

This page allows the definition of the environment of the system: Infinite or enclosed environment. Today only infinite environment is a free convection and air flow modes.

Convection definition:			
ambient temp	25 °C		
• free convection			
gravity orientation			
Oair flow	-z gravity z gravity xy gravity		PPAKS085 SC
flow orientation z		g	8
normal velocity (m/s)	1		
Simulation settings:		1 +	



STEP 4: SYSTEM DEFINITION

This page allows the definition of the environment of the system: Infinite or enclosed environment. Today only infinite environment is free convection and air flow modes.

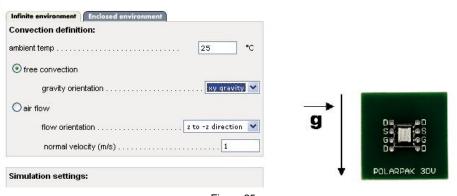


Figure 35.



ThermaSim[™] On-Line Thermal Simulation for Vishay Siliconix Power MOSFETs

STEP 4: SYSTEM DEFINITION

This page allows the definition of the environment of the system: Infinite or enclosed environment. Today only infinite environment is av free convection and air flow modes.

Convection definition:			
ambient temp	25 °C		
O free convection		$\overrightarrow{\mathbf{v}}$	
gravity orientation	z gravity 💌		e a
💽 air flow			
flow orientation	z to -z direction 💌	▲	
normal velocity (m/s)	z to -z direction -z to z direction x to -x direction -x to x direction	Z ****	
Simulation settings:	y to -y direction -y to -y direction -y to y direction	ł	
● steady state			

Figure 36.

STEP 4: SYSTEM DEFINITION

This page allows the definition of the environment of the system: Infinite or enclosed environment. Today only infinite environment is av free convection and air flow modes.

Infinite environment Enclosed environment	
Convection definition:	
ambient temp 25 °C	
O free convection	
gravity orientation z gravity 💌	
● air flow	≜
flow orientation	Z
normal velocity (m/s)	
Simulation settings:	
● steady state	
O transient	V
Figure 37.	

STEP 4: SYSTEM DEFINITION

This page allows the definition of the environment of the system: Infinite or enclosed environment. Today only infinite environment is available free convection and air flow modes.

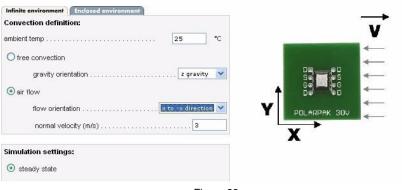


Figure 38.



ThermaSim[™] On-Line Thermal Simulation for Vishay Siliconix Power MOSFETs

STEP 4: SYSTEM DEFINITION

This page allows the definition of the environment of the system: Infinite or enclosed environment. Today only infinite environment is available free convection and air flow modes.

nfinite environment Enclosed environment	
Convection definition:	v
ambient temp 25 °C	
O free convection	→
gravity orientation z gravity 💙	
le air flow	
flow orientation	POLARPAK 300
normal velocity (m/s)	X
Simulation settings:	700.00
● steady state	

Figure 39.

STEP 4: SYSTEM DEFINITION

This page allows the definition of the environment of the system: Infinite or enclosed environment. Today only infinite environment is available free convection and air flow modes.

Infinite environment Enclosed environment	
Convection definition:	v
ambient temp 25 °C	
O free convection	\downarrow \downarrow \downarrow \downarrow \downarrow \downarrow \downarrow
gravity orientation	
I air flow	
flow orientation	A Ge H aG
normal velocity (m/s)	Y POLARPAK 300
Simulation settings:	×
⊙ steady state	~
O transient	
Figure 40.	

STEP 4: SYSTEM DEFINITION

This page allows the definition of the environment of the system: Infinite or enclosed environment. Today only infinite environment is available free convection and air flow modes.

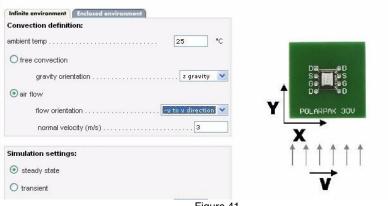


Figure 41.



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Simulation settings:		Simulation settings:	
 Steady state 		◯ steady state	
O transient		● transient	
initial time	0 s	initial time	1.0 s
final time	0 s	final time	1.1 S
time step	0.01 S	time step	0.01 S

Figure 43.

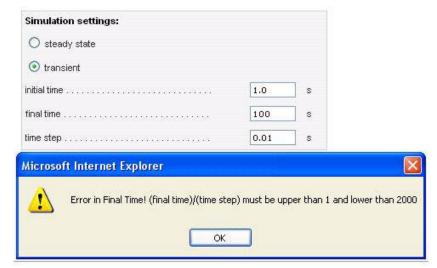


Figure 44.

A		
O steady state		
⊙ transient		
initial time	1.0	s
final time	1.1	s
time step	0.001	s

Figure 45.

Click on "Tab 5: Simulation Setup" at the top of the page to go to the next section.

Figure 42.

Clicking the **"Next"** icon at the bottom of the page also takes you to "Tab 5: Simulation Setup."





Tab 5: Simulation Setup

This section allows you to select the accuracy of simulation results, specify the email address of the recipient, save the configuration for future use, and to select the output data in a PDF format.

Simulation Settings:

Select Accuracy Level: The two pull-down menu options are **85 % or 95 %** (see Figure 46). Selecting 85 % accuracy gets simulation results within 5 °C to 10 °C while maintaining a reasonable file size and a quick turn around time for the results email. On the other hand, selecting 95 % accuracy gets simulation results up to 5 °C. However, this can take surprisingly long (even up to a day) to get the results email.

Enter recipient's **email** (address) in the adjacent **box** (see Figure 47).

Saving Configuration:

Enter a file name in the adjacent box.

Click the **"Save Configuration"** icon to save the work for future or repetitive use (refer to Figure 48). Later we will discuss how to load and use a saved configuration.

Output Data:

Select a **component** from the list to **highlight** (see Figure 49).

Check the boxes for the data you wish to receive.

Click the "Apply" icon.

Repeat all three steps for each component in the list.

Click the "Start Simulation" icon at the bottom of the page or select "Tab 6: Run."

The "Simulation Checking" window opens with list of all input data information for final review (refer to Figure 50). Click "Send" to send the acceptable data for simulation after review.

Click "Cancel" to go back and edit data if necessary. The pop-up message shown in Figure 51 confirms the successful submission of data.

Click "Close" to return the to design.

Clicking on the "Back" icon on any page takes you back to the previous page.

Also, **select any Tab in the top menu** to go to that section of the design.

Load a saved configuration:

Click on "Load" tab. The load page opens as shown in Figure 52. Click on the "Load Configuration" icon. The system refreshes to "Tab 1: Components." **Click** on **"Load"** again. This time the load window opens as shown in Figure 53, with one of the saved configuration's file names in the list window.

Click on **the pull down menu** to list all the saved configuration files, as shown in Figure 54. **Select** a file and click **"Open"** to load a file.

The design opens staring with "Tab 1: Components." Modify the design as necessary on any page, save it with

Delete a Saved Configuration:

different name, and run the simulation.

Select a file and click "Delete" to remove the unwanted configuration from the saved database.

?On-Line help

This menu is available on all pages of the design. A quick reference guide is available here.

?e-mail

This tab is available to send questions and comments for technical help. Include a snap shot of the screen to describe the problem. The latter helps generate prompt and accurate responses.

Simulation Results:

Refer to Figure 54, which is a snap shot of a simulation result email. The subject includes the name of the MOSFET component under study. The body of the email covers the simulation input data. There are two attachments: a result.pdf and a result.txt.

"result.pdf": The result.pdf document has three sections:

- Input Data (see Figure 55) This section lists all relevant design data.
- **Global Results** (see Figure 56) -This section lists the minimum and maximum temperature values of the system, and the flux, or power dissipated, through the PCB.
- Component Results (see Figure 57) This section lists the temperature values for the MOSFET component, such as minimum and maximum die temperatures, top and bottom temperatures of the package, and the flux to the PCB

"result.txt": The result.txt document lists output values in text format (see Figure 58). The latter facilitates data analysis while evaluating different scenarios.





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STEP 5: SIMULATION SETUP

This page allows to setup the configuration of the simulation. Steady state or computation is also parameterizable. This page also allows to save configural

Simulation settings:	
accuracy level	high (numerical accuracy = 95%) 💌
email	low (numerical accuracy = 85%) high (numerical accuracy = 95%)

Figure 46.

STEP 5: SIMULATION SETUP

This page allows to setup the configuration of the simulation. Steady state or t computation is also parameterizable. This page also allows to save configurat

Simulation settings:	
accuracy level	low (numerical accuracy = 85%) 💌
email	kpandya@Vishay.com

Figure 47.

Save configuration to database:	
config id	config_1
Save configurati	on

Figure 48.

pc SI SI	:b Tn (434 (434	nin T 6DY 6DY	ma: Tm Tm	x in in	Tr Tr	na	X X	т	di di	e e	T T	to)p	ר ר	гЬ	0	t	P P	h h	iT iT	0	P	c c	B
min	temp	.																						
ma:	×tem	р																						
die	temn																							

Output data selection:

	Apply	
flux to PCB		~
oot temp		~
op temp		~
die temp		~

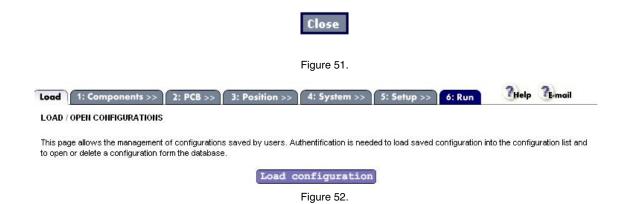
Figure 49.



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Simulation checking
Sinulation checking Components SI4346DV lengths(5.92, 4.82, 1.577) power = steady state (1W) center(18,18) pad(5.92,4.82) PCBsolder 100%solder0%air SI3436DV lengths(5.92, 4.82, 1.577) power = steady state (1.5W) center(9,9) pad(5.92,4.82) PCBsolder 100%solder0%air PCB size (25.4, 25.4) TopAverageLayer material = copper 100% thickness = 0.076 Layer 1 material = ER-4 Epoxy/Glass thickness = 0.076 Environment infinite environment natural convection gravity orientation: 2 ambiant temperature: 25 Setup transient simulation initial time: 1 final time: 1.1 time step:0.01 model accuracy: low e_mail kpandya@Vishay.com Units mm COutput pcb Tmin Tmax SI4346DV Tmin Tmax Tdie Ttop Tbot PhiToPCB SI4346DV Tmin Tmax Tdie Ttop Tbot PhiToPCB
Send run Cancel
Figure 50.
Simulation has been submited!

Results will be received by e-mail!





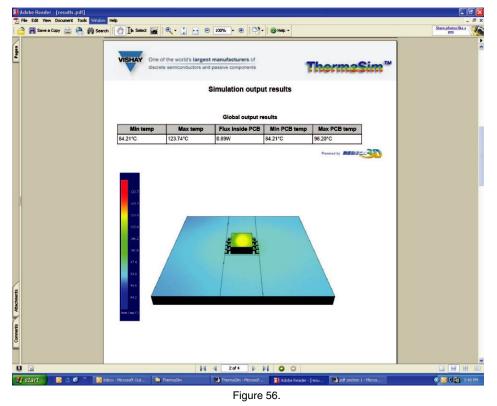
Load 1: Components >> 2: PCB >>	3: Position >> 4: System >> 5: Setup >> 6: Run 7Help 7E-mail
LOAD / OPEN CONFIGURATIONS	
This page allows the management of configuratio to open or delete a configuration form the databa	
	Load configuration
Availlable configurations for user kpandya@vis	shay.com:
	2xSi4346DY_1x1
	Open Delete
	Figure 53.
	Load configuration
	2xSi4346DY_1x1 ✓ Dell-Si4431BDY SiE800DF j-a si1305DL PolarPAK 1 PolarPAK 2 D2PAK 1 PolarPAK 3 Si4413BDY_050206 config_2 My FAE Si4431BDY_Datasheet Si3443BDV Si443BDV Si4346DY_1x1 Si4346DY_1x1 Si4346DY_1x1
	Figure 54.



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ve a Copy 🚔 🤮 🧌 Search 🥂 🕐 []	Select 📷 🔍 - 👔 😐 🛛	54% • 🛞 📑 • 🥑 Heb •	Create 200 fr		
VISHAY One of the	world's largest manuf	acturers of	-		
discrete sen	discrete semiconductors and passive components				
	Sim	ulation input data			
		Components			
component	position	power			
SI4346DY	(12.5000 , 12.5000)	steady 1.0000 W			
		PCB	•		
layer	material	thickness			
TopAverageLayer	copper 100%	0.0760 mm			
Layer_1	FR-4 Epoxy/Glass	1.4230 mm			
	copper 100%	0.0760 mm			
BotAverageLayer					
BotAverageLayer		Environment			
BotAverageLayer environment type	gravity orientat		1		

Figure 55.





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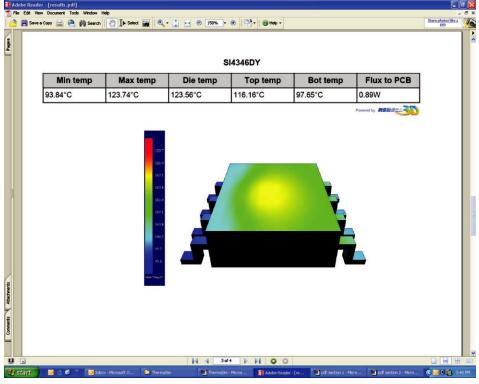


Figure 57.

Minimum system temperature = 84.21 °C Maximum system temperature = 123.74 °C Tot flux PCB = 0.89 W Tmin PCB = 84.21 °C Tmax PCB = 98.20 °C

Number of components = 1 SI4346DY Tmin = 93.84 °C SI4346DY Tmax = 123.74 °C SI4346DY Tdie = 123.56 °C SI4346DY Ttop = 116.16 °C SI4346DY Tbot = 97.65 °C SI4346DY PhitoPCB = 0.89 W

Figure 58.

Summary of Simulation Examples:

Appendix B Steady-state analysis for Si4368DY on FR4 1-in. x1-in., double-sided PCB with 2 oz. copper.

Appendix C Step transient simulation for SOIC-8.

Appendix D Cyclic transient simulation for DPAK, SUD.

Appendix E

Steady-state solution for D²PAK, DPAK, PowerPAK, and PolarPAK with heat sink and air flow.

For the appendices please refer to the following link:

http://www.vishay.com/doc?69535